NSN 5961-01-275-6575

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-275-6575 **Inclosure Material:** Metal **Overall Length:** 1.550 inches **Overall Height:** 0.300 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 500.0 drain to gate voltage and 500.0 drain to source voltage and 20.0 gate to source voltage **Current Rating Per Characteristic:** 15.00 amperes drain current **Power Rating Per Characteristic:** 250.0 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**